

SEMITOP[®]E2

IGBT module

SK75GD12T4ETE2

Features*

- Low inductive design
- · Press-Fit contact technology
- Rugged mounting due to integrated mounting clamps
- Heat transfer and insulation through direct copper bonded aluminium oxide ceramic (DBC)
- Trench4 IGBT technology
- Robust and soft switching CAL4F
 diode technology
- Integrated NTC temperature sensor
- UL recognized file no. E 63 532

Typical Applications

- Motor drives
- · Servo drives
- Air conditioning
- Auxiliary Inverters
- UPS

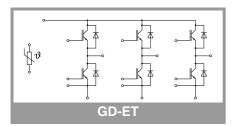
Absolute Maximum Ratings

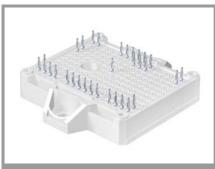
Symbol	Conditions		Values	Unit			
IGBT 1							
V _{CES}	T _j = 25 °C		1200	V			
lc	c λ _{paste} =0.8 W/(mK)	T _s = 25 °C	88	А			
	T _j = 175 °C	T _s = 70 °C	71	А			
I _C		T _s = 25 °C	113	А			
		T _s = 70 °C	92	А			
I _{Cnom}			75	А			
I _{CRM}	I _{CRM} = 3 x I _{Cnom}		225	А			
V_{GES}			-20 20	V			
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C	10	μs			
Tj		-	-40 175	°C			

Absolute Maximum Ratings

Symbol	Conditions		Values	Unit			
Diode 1							
V _{RRM}	T _j = 25 °C		1200	V			
l _F	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	79	А			
	T _j = 175 °C	T _s = 70 °C	62	А			
l _F	$ \begin{array}{c c} I_F & \lambda_{paste} = 2.5 \text{ W/(mK)} \\ T_j = 175 \ ^\circ\text{C} \end{array} $	T _s = 25 °C	101	Α			
		T _s = 70 °C	81	А			
I _{Fnom}			75	Α			
I _{FRM}	$I_{FRM} = 2 \times I_{Fnom}$		150	А			
I _{FSM} 10 ms	T _j = 25 °C	430	А				
	sin 180°	T _j = 150 °C	430	Α			
Tj		•	-40 175	°C			

Absolute Maximum Ratings					
Symbol	Conditions	Values	Unit		
Module					
I _{t(RMS)}	$\Delta T_{terminal}$ at PCB joint = 30 K, per pin	30	А		
T _{stg}		-40 125	°C		
V _{isol}	AC, sinusoidal, t = 1 min	2500	V		





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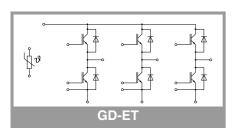
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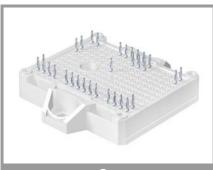
Typical Applications

- Motor drives
- Servo drives
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- · Auxiliary Inverters
- UPS

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT 1						
V _{CE(sat)}	l _C = 75 A	T _j = 25 °C		1.85	2.10	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.25	2.45	V
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V
	Chiplevel	T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		14	16	mΩ
	chiplevel	T _j = 150 °C		21	22	mΩ
V _{GE(th)}	$V_{GE} = V_{CE}, I_C = 3 \text{ m}$	A	5	5.8	6.5	V
I _{CES}	$V_{GE} = 0 V, V_{CE} = 12$	00 V, T _j = 25 °C			1	mA
Cies		f = 1 MHz		4.4		nF
Coes	$V_{CE} = 25 V$ $V_{GE} = 0 V$	f = 1 MHz		0.29		nF
C _{res}		f = 1 MHz		0.235		nF
Q _G	V _{GE} = -15V +15V			553		nC
R _{Gint}	T _j = 25 °C			10		Ω
t _{d(on)}	V _{CC} = 600 V	T _j = 150 °C		129		ns
t _r	$I_{\rm C} = 75 {\rm A}$	T _j = 150 °C		42		ns
Eon	$V_{GE} = +15/-15 V$ $R_{G on} = 1.1 \Omega$	T _j = 150 °C		6.62		mJ
t _{d(off)}	$R_{G off} = 1.1 \Omega$	T _j = 150 °C		333		ns
t _f	di/dt _{on} = 2410 A/µs di/dt _{off} = 593 A/µs	T _j = 150 °C		65		ns
E _{off}		T _j = 150 °C		7.11		mJ
R _{th(j-s)}	per IGBT, $\lambda_{paste}=0.8$ W/(mK)		_	0.61		K/W
R _{th(j-s)}	per IGBT, λ _{paste} =2.5 W/(mK)			0.39		K/W

Characteristics								
Symbol	Conditions		min.	typ.	max.	Unit		
Diode 1	Diode 1							
VF	I _F = 75 A	T _j = 25 °C		2.17	2.49	V		
	chiplevel	T _j = 150 °C		2.11	2.42	V		
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V		
		T _j = 150 °C		0.90	1.10	V		
r _F	- chiplevel	T _j = 25 °C		12	13	mΩ		
		T _j = 150 °C		16	18	mΩ		
I _{RRM}	di/dt _{off} = 2410 A/μs V _{GE} = -15 V	T _j = 150 °C		114		А		
Q _{rr}		T _j = 150 °C		11.22		μC		
E _{rr}		T _j = 150 °C		4.41		mJ		
R _{th(j-s)}	per Diode, $\lambda_{paste}=0.8 \text{ W/(mK)}$			0.82		K/W		
R _{th(j-s)}	per Diode, $\lambda_{paste}=2$.		0.55		K/W			





B_{100/125}

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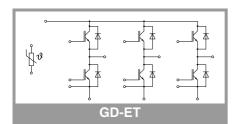
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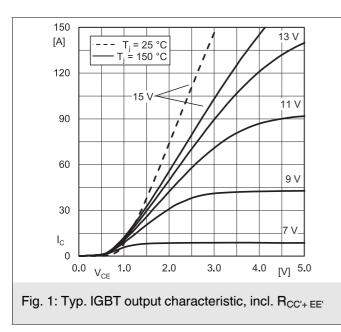
Characteristics							
Symbol	Conditions	min.	typ.	max.	Unit		
Module							
Ms	to heatsink	1.6		2.3	Nm		
w	weight		35		g		
Characteristics							
Symbol	Conditions	min.	typ.	max.	Unit		
Temperature Sensor							
R ₁₀₀	T _r = 100 °C	493 ± 5%		Ω			
D			3550		K		

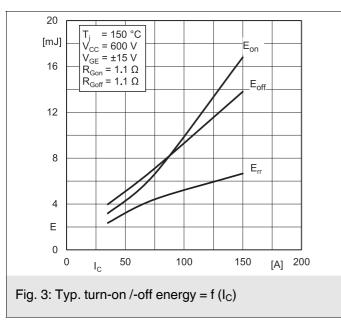
 $R_{(T)}=R_{100}exp[B_{100/125}(1/T-1/T_{100})]; T[K];$

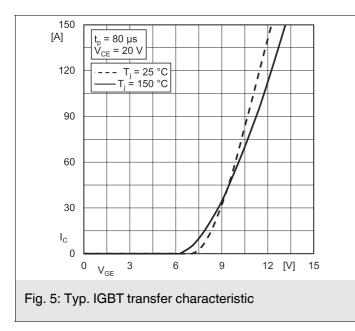


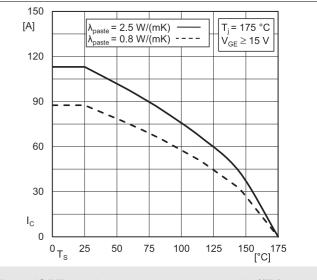
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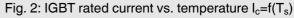
±2%

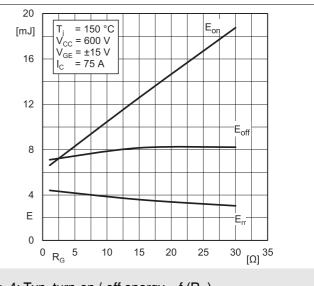


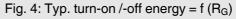


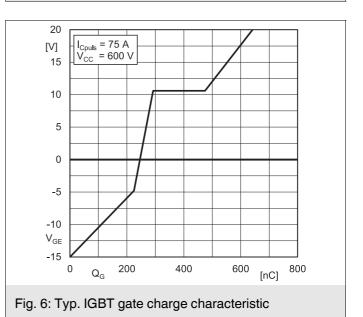




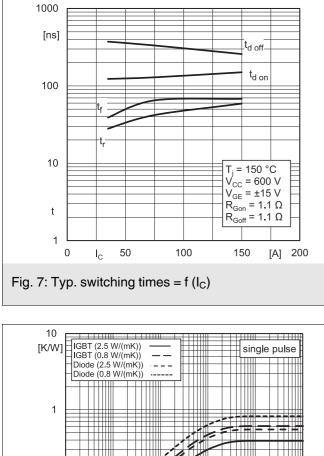


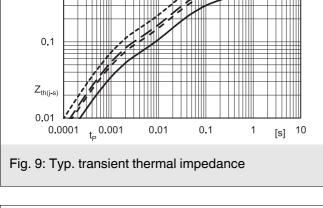


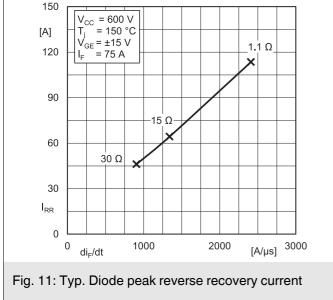


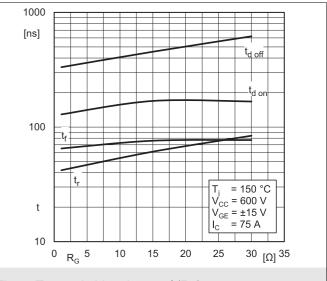


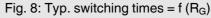
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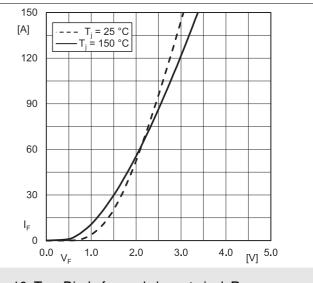
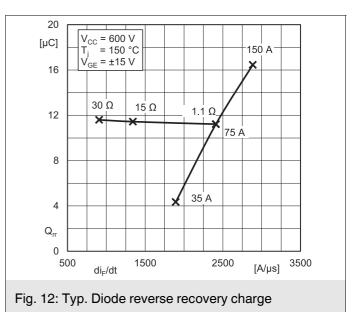
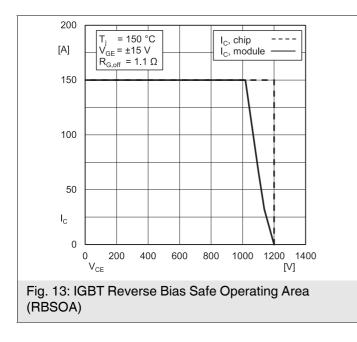
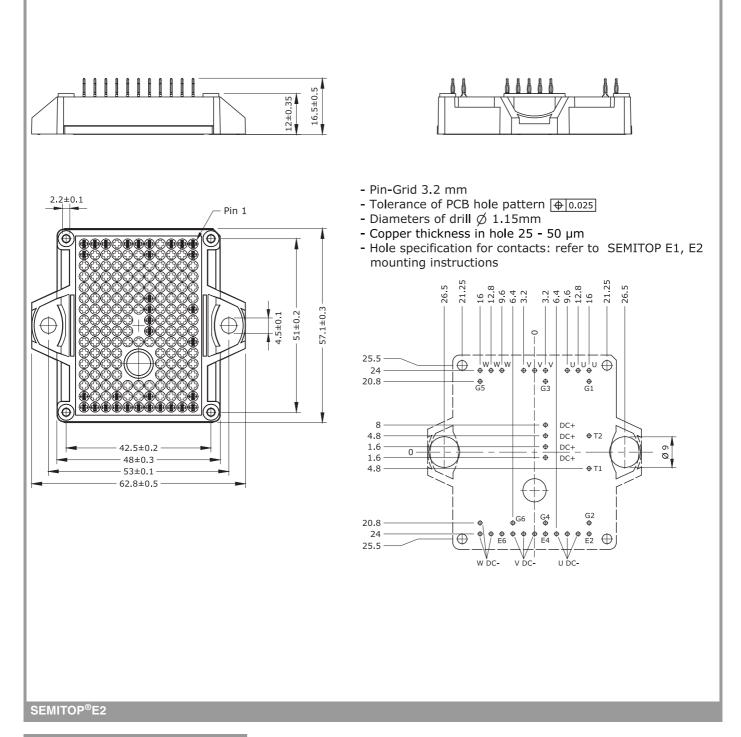
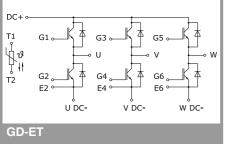


Fig. 10: Typ. Diode forward charact., incl. $R_{CC^{'+}\, EE^{'}}$









This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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